

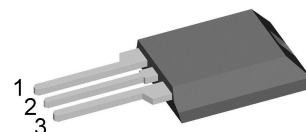
HiPerFRED

| | | |
|-----------|------|-------|
| V_{RRM} | = 2x | 600 V |
| I_{FAV} | = | 30 A |
| t_{rr} | = | 35 ns |

High Performance Fast Recovery Diode
Low Loss and Soft Recovery
Phase leg

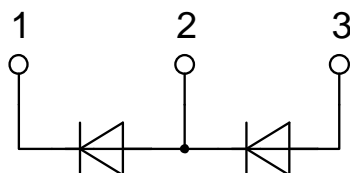
Part number

DSEE29-12CC



Backside: isolated

 E72873



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: ISOPLUS220

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Backside: DCB ceramic
- Reduced weight
- Advanced power cycling

Terms Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office.

Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office.

Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

- to perform joint risk and quality assessments;

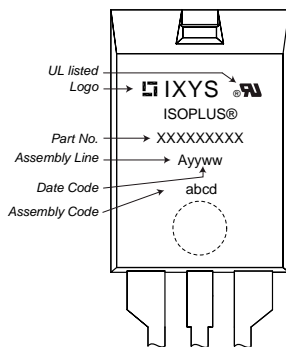
- the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

| Fast Diode | | | | Ratings | | | |
|------------|--|---|-------------------------|---------|------|------------|--|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit | |
| V_{RSM} | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}C$ | | | 600 | V | |
| V_{RRM} | max. repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}C$ | | | 600 | V | |
| I_R | reverse current, drain current | $V_R = 600 V$ | $T_{VJ} = 25^{\circ}C$ | | 500 | μA | |
| | | $V_R = 600 V$ | $T_{VJ} = 150^{\circ}C$ | | 1 | mA | |
| V_F | forward voltage drop | $I_F = 30 A$ | $T_{VJ} = 25^{\circ}C$ | | 1.62 | V | |
| | | $I_F = 60 A$ | | | 1.95 | V | |
| | | $I_F = 30 A$ | $T_{VJ} = 150^{\circ}C$ | | 1.27 | V | |
| | | $I_F = 60 A$ | | | 1.58 | V | |
| I_{FAV} | average forward current | $T_C = 130^{\circ}C$ rectangular $d = 0.5$ | $T_{VJ} = 175^{\circ}C$ | | 30 | A | |
| V_{FO} | threshold voltage | } for power loss calculation only | $T_{VJ} = 175^{\circ}C$ | | 1.00 | V | |
| r_F | slope resistance | | | | 10 | m Ω | |
| R_{thJC} | thermal resistance junction to case | | | | 0.9 | K/W | |
| R_{thCH} | thermal resistance case to heatsink | | | 0.50 | | K/W | |
| P_{tot} | total power dissipation | | $T_C = 25^{\circ}C$ | | 165 | W | |
| I_{FSM} | max. forward surge current | $t = 10 ms; (50 Hz), sine; V_R = 0 V$ | $T_{VJ} = 45^{\circ}C$ | | 200 | A | |
| C_J | junction capacitance | $V_R = 400 V$ $f = 1 MHz$ | $T_{VJ} = 25^{\circ}C$ | | 26 | pF | |
| I_{RM} | max. reverse recovery current | } $I_F = 30 A; V_R = 300 V$ $-di_F / dt = 600 A/\mu s$ | $T_{VJ} = 25^{\circ}C$ | | 17 | A | |
| | | | $T_{VJ} = 100^{\circ}C$ | | 29 | A | |
| t_{rr} | reverse recovery time | | $T_{VJ} = 25^{\circ}C$ | | 35 | ns | |
| | | | $T_{VJ} = 100^{\circ}C$ | | 90 | ns | |

| Package ISOPLUS220 | | Ratings | | | | |
|--------------------|--|----------------------|------|------|------|------|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
| I_{RMS} | RMS current | per terminal | | | 35 | A |
| T_{VJ} | virtual junction temperature | | -55 | | 175 | °C |
| T_{op} | operation temperature | | -55 | | 150 | °C |
| T_{stg} | storage temperature | | -55 | | 150 | °C |
| Weight | | | | 2 | | g |
| F_C | mounting force with clip | | 20 | | 60 | N |
| $d_{Spp/App}$ | creepage distance on surface striking distance through air | terminal to terminal | 1.0 | | | mm |
| $d_{Spb/Apb}$ | | terminal to backside | 3.0 | | | mm |
| V_{ISOL} | isolation voltage | t = 1 second | 3600 | | | V |
| | | t = 1 minute | 3000 | | | V |

Product Marking



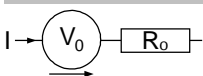
| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | DSEE29-12CC | DSEE29-12CC | Tube | 50 | 500694 |

| Similar Part | Package | Voltage class |
|--------------|--------------|---------------|
| DSEE30-12A | TO-247AD (3) | 600 |

Equivalent Circuits for Simulation

* on die level

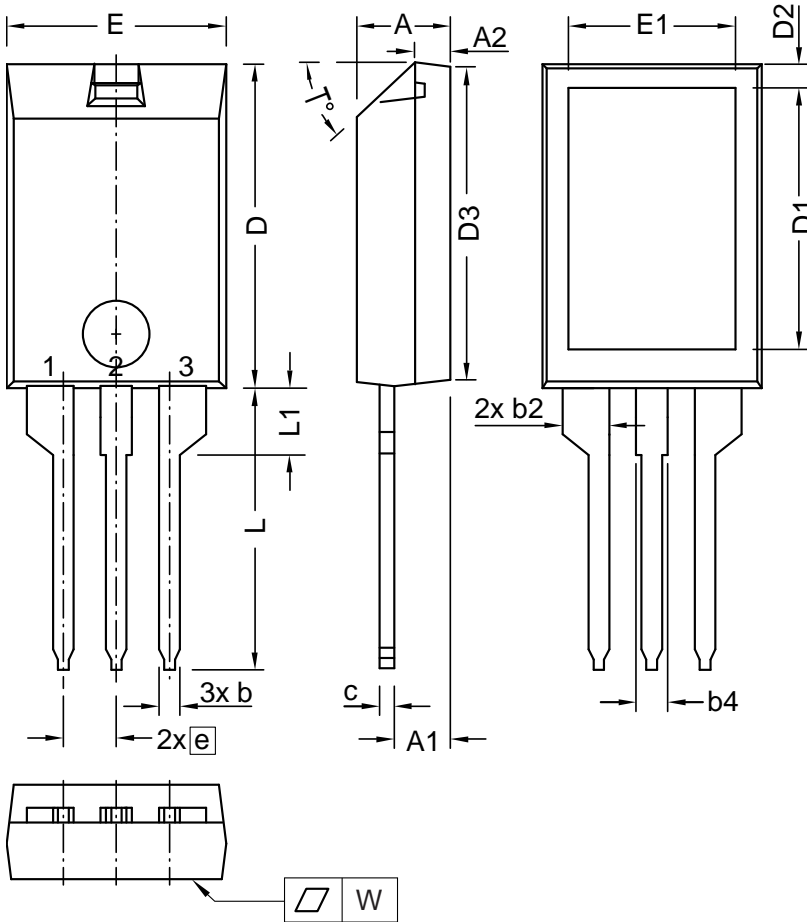
$T_{VJ} = 175\text{ °C}$



Fast Diode

| | | | |
|--------------|--------------------|-----|----|
| $V_{0\ max}$ | threshold voltage | 1 | V |
| $R_{0\ max}$ | slope resistance * | 6.2 | mΩ |

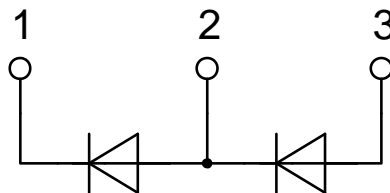
Outlines ISOPLUS220



| Dim. | Millimeters | | Inches | |
|------|-------------|-------|-----------|-------|
| | min | max | min | max |
| A | 4.00 | 5.00 | 0.157 | 0.197 |
| A1 | 2.50 | 3.00 | 0.098 | 0.118 |
| A2 | 1.60 | 1.80 | 0.063 | 0.071 |
| b | 0.90 | 1.30 | 0.035 | 0.051 |
| b2 | 2.35 | 2.55 | 0.093 | 0.100 |
| b4 | 1.25 | 1.65 | 0.049 | 0.065 |
| c | 0.70 | 1.00 | 0.028 | 0.039 |
| D | 15.00 | 16.00 | 0.591 | 0.630 |
| D1 | 12.00 | 13.00 | 0.472 | 0.512 |
| D2 | 1.10 | 1.50 | 0.043 | 0.059 |
| D3 | 14.90 | 15.50 | 0.587 | 0.610 |
| E | 10.00 | 11.00 | 0.394 | 0.433 |
| E1 | 7.50 | 8.50 | 0.295 | 0.335 |
| e | 2.54 BSC | | 0.100 BSC | |
| L | 13.00 | 14.50 | 0.512 | 0.571 |
| L1 | 3.00 | 3.50 | 0.118 | 0.138 |
| T° | 42.5 | 47.5 | | |
| W | - | 0.1 | - | 0.004 |

Die konvexe Form des Substrates ist typ. < 0.04 mm über der Kunststoffoberfläche der Bauteilunterseite
 The convex bow of substrate is typ. < 0.04 mm over plastic surface level of device bottom side

Die Gehäuseabmessungen entsprechen dem Typ TO-273 gemäß JEDEC außer D und D1.
 This drawing will meet all dimensions requirement of JEDEC outline TO-273 except D and D1.



Fast Diode

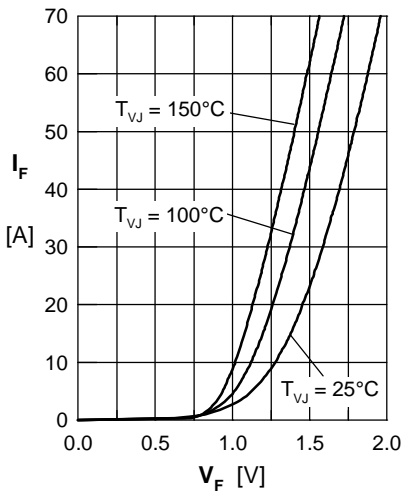


Fig. 1 Forward current I_F vs. V_F

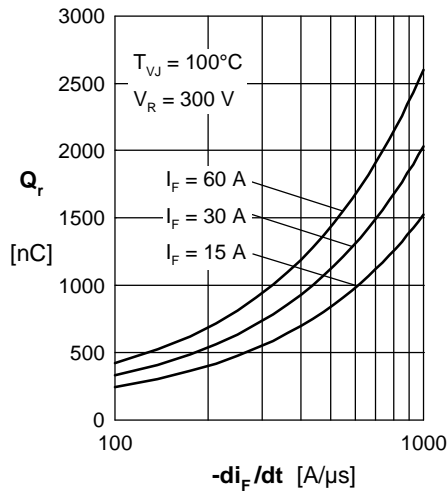


Fig. 2 Typ. reverse recovery charge Q_r versus $-di_F/dt$

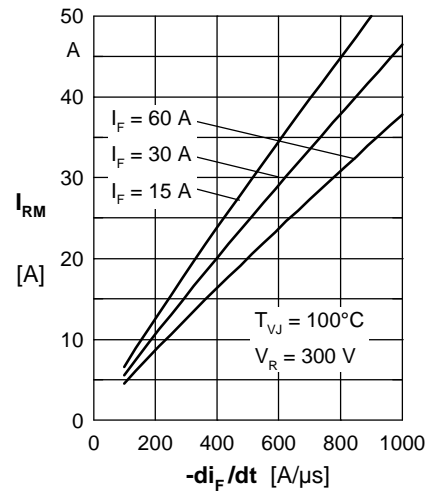


Fig. 3 Typ. peak reverse current I_{RM} versus $-di_F/dt$

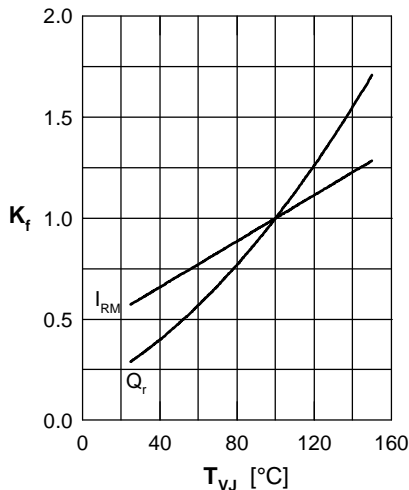


Fig. 4 Dynamic parameters Q_r , I_{RM} versus T_{VJ}

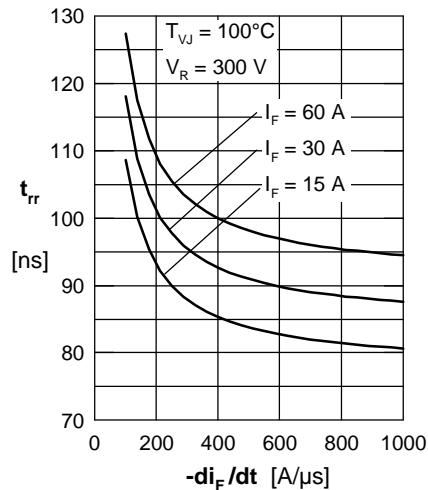


Fig. 5 Typ. recovery time t_{tr} versus $-di_F/dt$

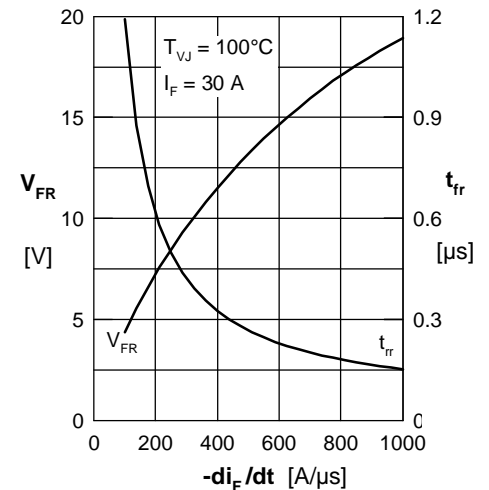


Fig. 6 Typ. peak forward voltage V_{FR} and typ. forward recovery time t_{fr} versus di_F/dt

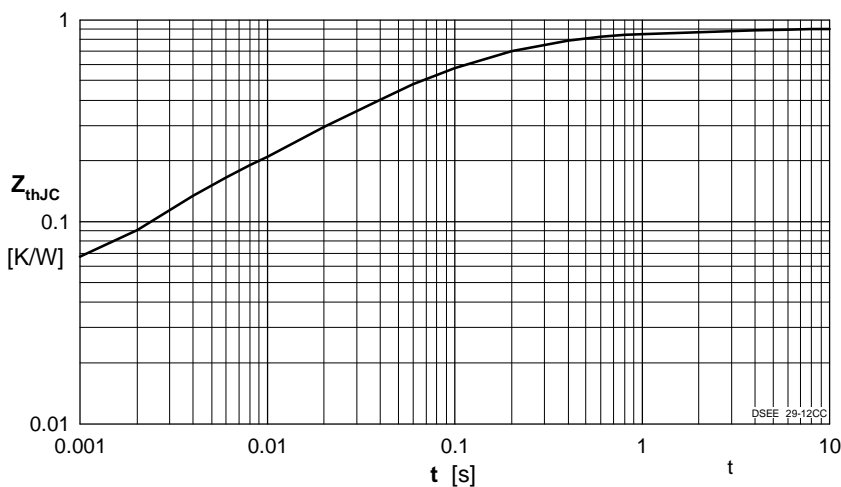


Fig. 7 Transient thermal resistance junction to case

Constants for Z_{thJC} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|---|-----------------|-----------|
| 1 | 0.038 | 0.00024 |
| 2 | 0.07 | 0.0036 |
| 3 | 0.245 | 0.0235 |
| 4 | 0.198 | 0.1421 |
| 5 | 0.35 | 0.25 |



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.